

Supporting Information

for

Efficient liquid exfoliation of KP_{15} nanowires aided by Hansen's empirical theory

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Strong temperature-dependent Raman response of exfoliated KP₁₅

The KP₁₅ nanowires with a defect-free surface and high carrier mobility are suitable for the development of novel electric nanodevices. The vibrational properties of KP₁₅ nanowires can play an important role in the electronic performance of nanodevices [1]. Here we found that exfoliated KP₁₅ nanowires had a strong temperature-dependent Raman response. Due to the resolution of the Raman system at a low-temperature mode, a KP₁₅ nanowire with a thickness of 80.9 nm and a width of 139.1 nm was chosen for the temperature-dependent Raman test (Figure S1a and Figure S1b). When the laser power values were 20 and 80 μ w, respectively, the positions of those Raman peaks were the same (Figure S1c). This means that when the laser power was below 80 µw, the laser heating did not significantly increase the temperature of the KP₁₅ nanowires. Here, for low-temperature Raman measurements, the laser power was kept below 20 μW. Figure S1d shows Raman spectra of the tested KP₁₅ nanowire under different temperatures. The space group of KP_{15} is $P\overline{1}$, so all the Raman peaks in KP_{15} are in the Ag mode. There were seven Raman peaks with a high signal-to-noise ratio located at 90.6, 126.1, 354.2, 369.6, 378.7, 453.9, and 476.2 cm⁻¹. These peaks were named as No. 1, 4, 7, 8, 9, 11, and 12 Raman peaks for an easy identification in Figure S1d. As the temperature increased, all the Raman peaks of the liquid-exfoliated KP₁₅ nanowire shifted towards lower wave numbers (Figure S1). The vibration frequencies of those Raman peaks have a linear relationship with temperature (Figure S2). The peak position and temperature data can be fitted by the following the Equation S1.

$$\omega = \omega_0 + \chi T,\tag{S1}$$

where ω_0 is the vibration frequency of the corresponding Raman mode at absolute zero, χ is the first-order temperature coefficient of the Raman mode, and ω is the vibration frequency of the Raman mode at T [2]. The second-order term was not considered because it usually appeared at high temperature. The temperature evolutions of those Raman modes in the tested KP₁₅ are shown in Figure S2. For peak 1, χ_1 =-0.00942 cm⁻¹K⁻¹; for peak 4, χ_4 =-0.01756 cm⁻¹K⁻¹; for peak7, χ_7 =-0.02118 cm⁻¹K⁻¹; for peak 8, χ_8 =-0.02065 cm⁻¹K⁻¹; for peak 9, χ_9 =-0.01327 cm⁻¹K⁻¹; for peak 11, χ_{11} =-0.01892 cm⁻¹K⁻¹; and for peak 12, χ_{12} =-0.01724 cm⁻¹K⁻¹. The highest temperature coefficient (χ_7 =-0.02118 cm⁻¹K⁻¹) in

 KP_{15} nanowire Raman modes is near to the highest value of black phosphorus (-0.028 cm⁻¹K⁻¹) and is higher than the highest value of MoS_2 (-0.0132 cm⁻¹K⁻¹) and graphene (-0.016 cm⁻¹K⁻¹) [2-4].

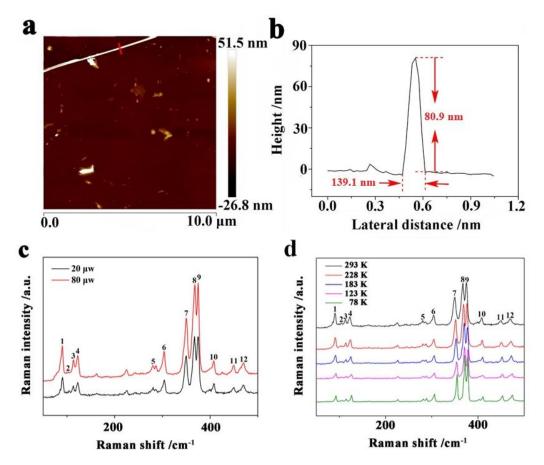


Figure S1: The size of the tested KP₁₅ nanowire and its Raman results at different temperatures. (a) Optical result of the tested KP₁₅ nanowire. (b) AFM result of the tested KP₁₅ nanowire marked in Figure S1a. (c) Raman results of the tested KP₁₅ nanowire marked in Figure S1a with different laser power values at room temperature. (d) Raman results of the tested KP₁₅ nanowire marked in Figure S1a at different temperatures.

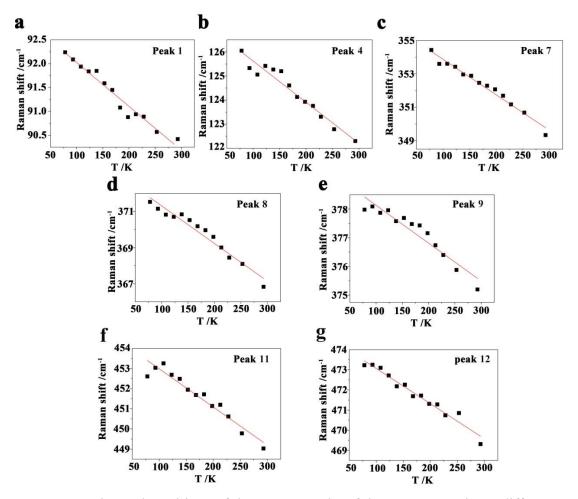


Figure S2: The peak positions of the Raman peaks of the KP₁₅ nanowire at different temperatures. Temperature dependence of Raman peaks No. 1(a), 4(b), 7(c), 8(d), 9(e), 11(f), 12(g).

The frequency changes could be attributed to two reasons: the anharmonic coupling of phonons and phonon energy changes caused by thermal expansion of the lattice [4]. The measured frequency change $\Delta\omega$ can be written as:

$$\triangle \omega = (\chi_T + \chi_V) \triangle_T = \left(\frac{d\omega}{dT}\right)_V \triangle T + \left(\frac{d\omega}{dV}\right)_T \triangle V, \tag{S2}$$

where χ_T is the "self-energy" shift due to the direct coupling of the phonon modes and χ_V is the shift due to the thermal-expansion-induced volume change [5]. However, concrete contributions of "self-energy" and thermal expansion to the temperature coefficient in KP_{15} still lack theoretical research. Due to the lower thermal expansion of KP_{15} (4.84×10⁻⁶K⁻¹) [6], the temperature coefficient of KP_{15} nanowires is mainly due to the contribution of "self-energy" rather than to thermal expansion [4]. Therefore,

the strong temperature-dependent Raman response indicates a strong phonon–phonon coupling in KP_{15} nanowires. This result may help with non-invasive temperature measurements of KP_{15} nanodevices.

References

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